TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

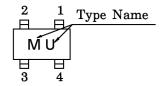
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VHF~UHF BAND LOW NOISE AMPLIFIER APPLICATIONS

MAXIMUM RATINGS (Ta = 25°C)

| CHARACTERISTIC | SYMBOL | RATING | UNIT |
|-----------------------------|--------------------|---------|----------------------|
| Collector-Base Voltage | v_{CBO} | 8 | V |
| Collector-Emitter Voltage | v_{CEO} | 5 | V |
| Emitter-Base Voltage | v_{EBO} | 1.5 | V |
| Collector Current | $I_{\mathbf{C}}$ | 10 | mA |
| Base Current | $I_{\mathbf{B}}$ | 5 | mA |
| Collector Power Dissipation | PC | 100 | mW |
| Junction Temperature | T_{j} | 125 | °C |
| Storage Temperature Range | $T_{ m stg}$ | -55~125 | $^{\circ}\mathrm{C}$ |

Marking



MICROWAVE CHARACTERISTICS (Ta = 25°C)

1, 3. EMITTER 2. BASE 4. COLLECTOR USQ JEDEC — EIAJ — TOSHIBA 2-2K1A

Weight: 0.006 g

| CHARACTERISTIC | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|----------------------|-------------------|---|------|------|------|------|
| Transition Frequency | ${f f_T}$ | $ m V_{CE}=3~V,~I_{C}=7~mA$ | 13 | 16 | _ | GHz |
| Tinsertion (fain | $ S_{21e} ^2$ (1) | $V_{CE} = 3 V$, $I_{C} = 7 mA$, $f = 1 GHz$ | 14.5 | 17.5 | _ | dB |
| | $ S_{21e} ^2$ (2) | $V_{CE} = 3 V, I_{C} = 7 mA, f = 2 GHz$ | 9 | 12 | _ | |
| I Noise Kigure | NF (1) | $V_{CE} = 3 V, I_{C} = 3 mA, f = 1 GHz$ | _ | 0.9 | 1.8 | dB |
| | NF (2) | $V_{CE} = 3 V, I_{C} = 3 mA, f = 2 GHz$ | _ | 1.4 | 2.3 | ub |

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| CHARACTERISTIC | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|------------------------------|-------------------|--------------------------------------|------|------|------|---------|
| Collector Cut-off Current | I_{CBO} | $V_{CB} = 8 V, I_{E} = 0$ | _ | _ | 1 | μ A |
| Emitter Cut-off Current | $I_{ m EBO}$ | $V_{EB} = 1 V, I_{C} = 0$ | _ | _ | 1 | μ A |
| DC Current Gain | $h_{	ext{FE}}$ | $V_{CE} = 3 V, I_{C} = 7 mA$ | 50 | _ | 250 | V |
| Output Capacitance | $C_{ m ob}$ | $V_{CB} = 2.5 \text{ V}, I_{E} = 0,$ | _ | 0.4 | _ | рF |
| Reverse Transfer Capacitance | $\mathrm{C_{re}}$ | f = 1 MHz (Note) | _ | 0.3 | 0.7 | pF |

(Note): Cre is measured by 3 terminal method with Capacitance Bridge.

CAUTION

This device electrostatic sensitivity. Please handle with caution.

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